

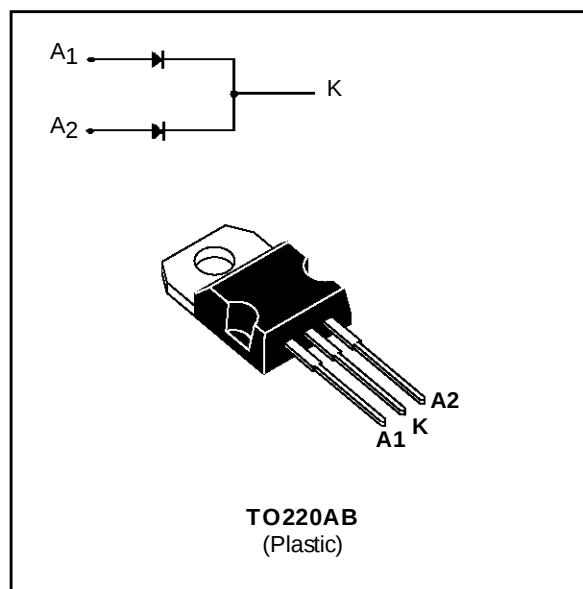
ULTRA FAST RECOVERY RECTIFIER DIODES

- SUITED FOR SMPS
- LOW LOSSES
- LOW FORWARD AND REVERSE RECOVERY TIME
- HIGH SURGE CURRENT CAPABILITY
- HIGH AVALANCHE ENERGY CAPABILITY

DESCRIPTION

Low cost dual center tap rectifier suited for switch-mode power supply and high frequency DC to DC converters.

Packaged in TO220AB, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter			Value	Unit
$I_F(RMS)$	RMS Forward Current		Per diode	30	A
$I_F(AV)$	Average Forward Current	$T_c = 115^\circ C$ $\delta = 0.5$	Per diode Per device	12 24	A
I_{FSM}	Surge Non Repetitive Forward Current	$T_p = 10\text{ ms}$ Sinusoidal	Per diode	120	A
T_{stg} T_J	Storage and Junction Temperature Range			- 65 to + 150 - 65 to + 150	$^\circ C$

Symbol	Parameter	STPR		Unit
		2410CT	2420CT	
V_{RRM}	Repetitive Peak Reverse Voltage	100	200	V

THERMAL RESISTANCE

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction-case	Per diode total	2.5 1.4	$^\circ C/W$
$R_{th(c)}$	Coupling		0.23	$^\circ C/W$

When the diodes 1 and 2 are used simultaneously :
 $\Delta T_J(\text{diode } 1) = P(\text{diode } 1) \times R_{th}(\text{Per diode}) + P(\text{diode } 2) \times R_{th}(c)$

STPR2410CT/STPR2420CT

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Tests Conditions		Min.	Typ.	Max.	Unit
I_R^*	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			50	μA
	$T_j = 100^\circ\text{C}$				0.8	mA
V_F^{**}	$T_j = 125^\circ\text{C}$	$I_F = 12\text{ A}$			0.99	V
	$T_j = 125^\circ\text{C}$	$I_F = 24\text{ A}$			1.20	
	$T_j = 25^\circ\text{C}$	$I_F = 24\text{ A}$			1.25	

Pulse test : * $t_p = 5\text{ ms}$, duty cycle $< 2\%$

** $t_p = 380\text{ }\mu\text{s}$, duty cycle $< 2\%$

RECOVERY CHARACTERISTICS

Symbol	Tests Conditions		Min.	Typ.	Max.	Unit
t_{rr}	$T_j = 25^\circ\text{C}$	$I_F = 0.5\text{ A}$ $I_R = 1\text{ A}$ $I_{rr} = 0.25\text{ A}$			30	ns
t_{fr}	$T_j = 25^\circ\text{C}$	$I_F = 1\text{ A}$ $t_r = 10\text{ ns}$ $V_{FR} = 1.1 \times V_F$		20		ns
V_{FP}	$T_j = 25^\circ\text{C}$	$I_F = 1\text{ A}$ $t_r = 10\text{ ns}$		3		V

To evaluate the conduction losses use the following equation :

$$P = 0.78 \times I_{F(AV)} + 0.0175 I_F^2(RMS)$$

Fig.1 : Average forward power dissipation versus average forward current. (Per diode)

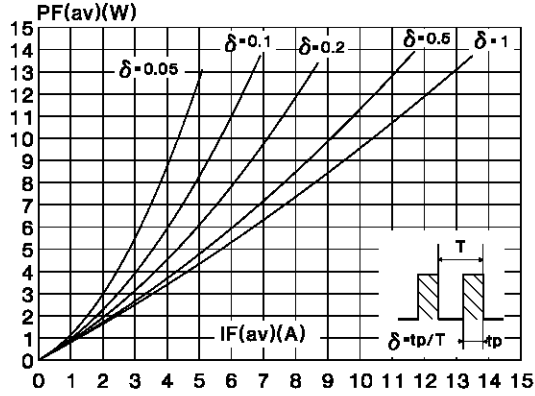


Fig.2 : Peak current versus form factor. (Per diode)

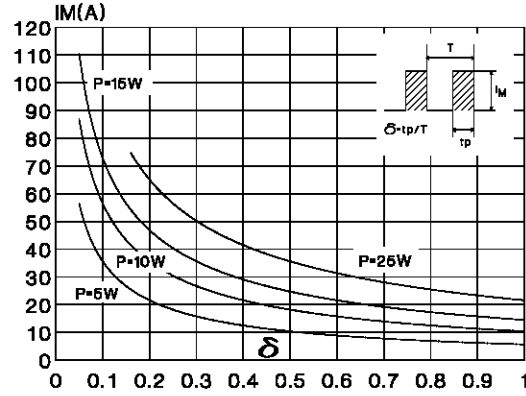


Fig.3 : Average current versus ambient temperature. (duty cycle : 0.5) (Per diode)

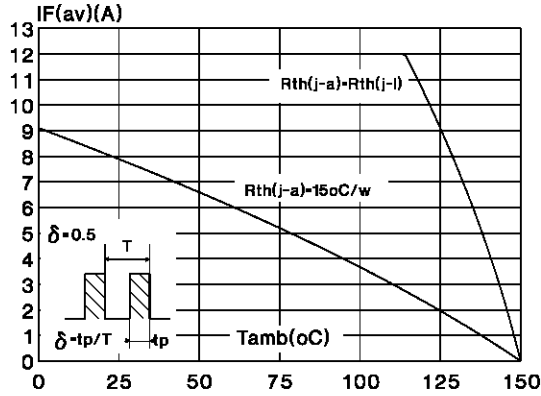


Fig.4 : Non repetitive surge peak forward current versus overload duration. (Maximum values)

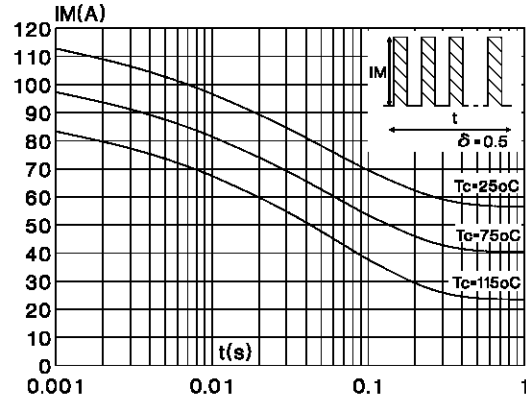


Fig.5 : Relative variation of thermal transient impedance junction to case versus pulse duration. (Per diode)

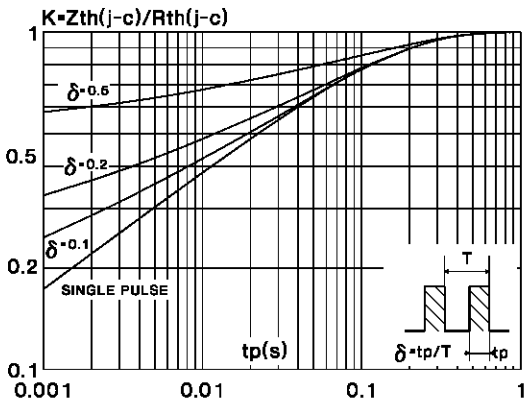
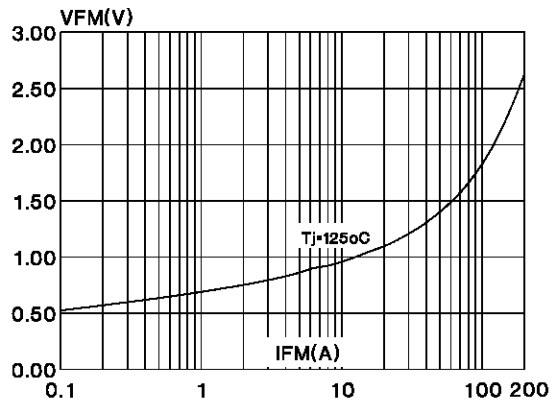


Fig.6 : Forward voltage drop versus forward current. (Maximum values) (Per diode)



STPR2410CT/STPR2420CT

Fig.7 : Junction capacitance versus reverse voltage applied. (Typical values) (Per diode)

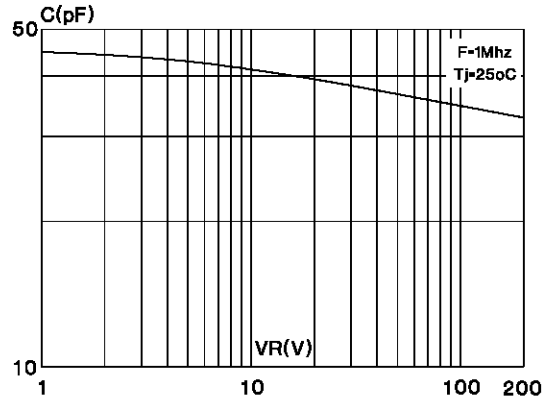


Fig.8 : Recovery charge versus dI_F/dt . (Per diode)

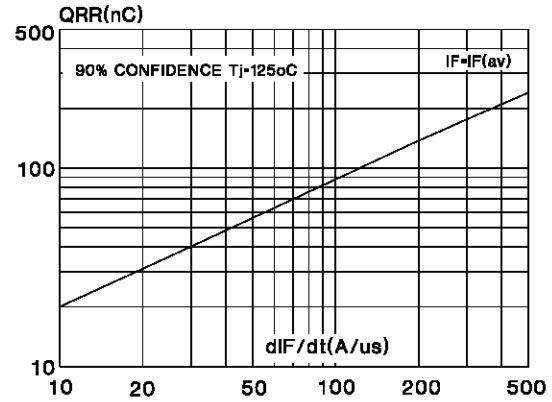


Fig.9 : Peak reverse current versus dI_F/dt . (Per diode)

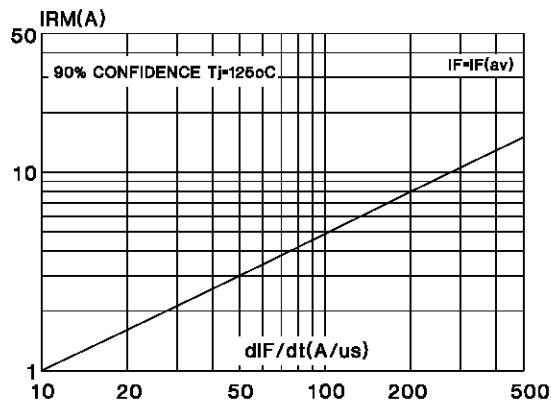
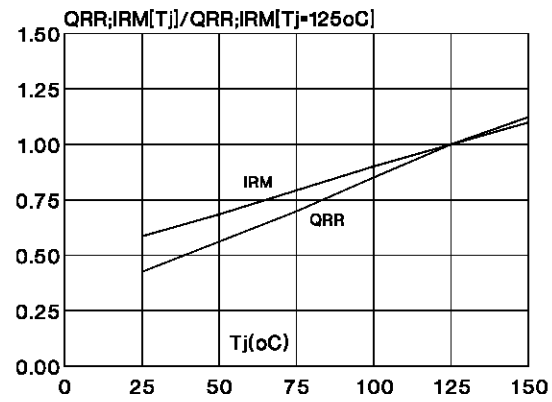
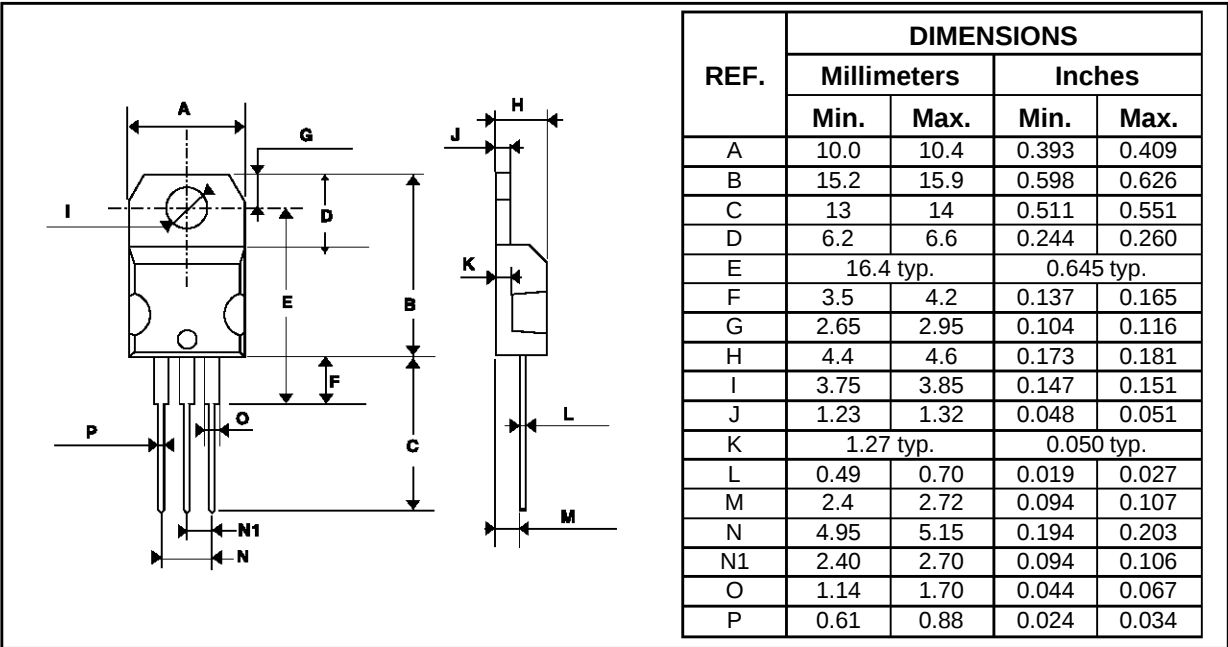


Fig.10 : Dynamic parameters versus junction temperature. (Per diode)



PACKAGE MECHANICAL DATA
TO220AB (JEDEC outline)



Cooling method : C
Marking : Type number
Weight : 2 g
Recommended torque value : 0.55m.N
Maximum torque value : 0.7m.N

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